

## Low-Voltage, Dual Supply, Low R<sub>ON</sub>, Quad SPST Analog Switches

#### **DESCRIPTION**

The DG9424, DG9425, DG9426 are low voltage precision monolithic quad single-pole-single-throw analog switches.

Using BiCMOS wafer fabrication technology allows the DG9424, DG9425, DG9426 to operate on single and dual supplies. Single supply voltage ranges from 3 to 12 V while dual supply operation is recommended with  $\pm$  3 to  $\pm$  6 V.

Combining high speed ( $t_{ON}$ : 42 ns), flat  $R_{DS(on)}$  over the analog signal range ( $\Omega$ ), minimal insertion lose (- 3 dB at 190 MHz), and excellent crosstalk and off-isolation performance, the DG9424, DG9425, DG9426 are ideally suited for audio and video signal switching.

The DG9424 and DG9425 respond to opposite control logic as shown in the Truth Table. The DG9426 has two normally open and two normally closed switches.

#### **FEATURES**

- 2.7 V thru 12 V single supply or ± 3 thru ± 6 dual supply
- On-resistance R<sub>DS(on):</sub> 1.7 Ω
- Fast switching t<sub>ON</sub>: 42 ns
  - t<sub>OFF</sub>: 28 ns
- TTL, CMOS compatible
- Low leakage: 0.2 nA
- · 2000 V ESD protection

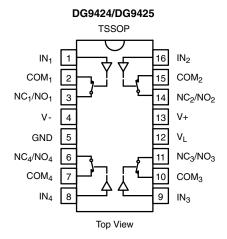
#### **BENEFITS**

- · Widest dynamic range
- · Low signal errors and distortion
- · Break-before-make switching action
- · Simple interfacing

#### **APPLICATIONS**

- · Automatic test equipment
- · Data acquisition systems
- Communication systems
- · ADC systems
- xDSL and PBX/PABX
- · Audio signal routing

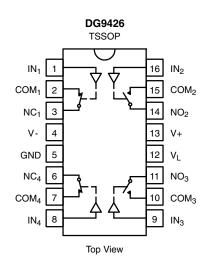
#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE						
Logic	DG9424	DG9425				
0	OFF	ON				
1	ON	OFF				



#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE						
Logic	SW <sub>1</sub> , SW <sub>4</sub>	$SW_2, SW_3$				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION								
Temp. Range	Package	Part Number						
DG9424, DG9425								
- 40 °C to 85 °C	16-Pin TSSOP	DG9424DQ						
- 40 C to 65 C	16-FIII 1330F	DG9425DQ						
DG9426								
- 40 °C to 85 °C	16-Pin TSSOP	DG9426DQ						

ABSOLUTE MAXIMUM RATINGS						
Parameter	Limit	Unit				
V+ to V-	- 0.3 to 13					
GND to V-		7	V			
V <sub>L</sub>	(GND - 0.3) to (V+) + 0.3	7 v				
IN, COM, NC, NO <sup>a</sup>	- 0.3 to (V+ + 0.3)	1				
Continuous Current (NO, NC, COM Pins)	100	mA				
Peak Current, S or D (Pulsed 1 ms, 10 % D	200	- IIIA				
Storage Temperature		- 65 to 150	°C			
Power Dissipation (Package) <sup>b</sup>	16-Pin TSSOP <sup>c</sup>	450	mW			
Thermal Resistance <sup>b</sup>	10-211 13302	178	°C/W			

#### Notes:

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 7 mW/°C above 25 °C.



		Test Conditions Unless Specified $V+ = 12 V, V- = 0 V$		Limits - 40 °C to 85 °C		°C	
Parameter	Symbol	$V_L = 5 \text{ V}, V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp.b	Min. <sup>d</sup>	Typ. <sup>c</sup>	Ma.x <sup>d</sup>	Uni
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0		12	V
On-Resistance	R <sub>ON</sub>	V+ = 10.8  V, V- = 0  V $I_{NO}, I_{NC} = 50 \text{ mA}, V_{COM} = 2/9 \text{ V}$	Room Full		1.8	3 4	Ω
Digital Control							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	- 1	0.01	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	$R_L = 300 \Omega$ , $C_L = 35 pF$	Room Full		42	57 65	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC} = 5$ V, See Figure 2	Room Full		28	42 44	ns
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 Only, $V_{NO}$ , $V_{NC} = 5 V$ $R_L = 300 \Omega$ , $C_L = 35 pF$	Room	2			
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		38		рС
Off-Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room		- 56		45
Channel-to-Channel Crosstalk <sup>e</sup>	X <sub>TALK</sub>	f = 1 MHz	Room		- 77		dE
NO, NC Off Capacitance <sup>e</sup>	C <sub>NO(off)</sub> C <sub>NC(off)</sub>		Room		49		
COM Off Capacitance <sup>e</sup>	C <sub>COM(off)</sub>	f = 1 MHz	Room		37		pl
Channel On Capacitance <sup>e</sup>	C <sub>COM(on)</sub>		Room		89		
Power Supplies			_		l .		
Positive Supply Current	l+		Room Full		0.02	1 5	
Negative Supply Current	I-	V 0 2 7 V	Room Full	- 1 - 5	- 0.002		
Logic Supply Current	IL	$V_{IN} = 0$ or $V_{L}$	Room Full		0.002	1 5	μ
Ground Current	I <sub>GND</sub>		Room Full	- 1 - 5	- 0.002		

# DG9424, DG9425, DG9426

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		Test Conditions Unless Specified $V+=5 V$ , $V-=5 V$		<b>Limits</b> - 40 °C to 85 °C			
Parameter	Symbol	$V_L = 5 \text{ V}, V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp.b	Min.d	Typ.c	Max.d	Unit
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	- 5		5	V
On-Resistance	R <sub>ON</sub>	V + = 4.5  V, V - = -4.5  V $I_{NO}, I_{NC} = 50 \text{ mA}, V_{COM} = \pm 3.5 \text{ V}$	Room Full		2	3.3 4.3	Ω
Switch Off Leakage Current	I <sub>NO(off)</sub>	V+ = 5.5 V, V- = - 5.5 V	Room Full	- 1 - 10		1 10	
Owner on Leakage Ourient	I <sub>COM(off)</sub>	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room Full	- 1 - 10		1 10	nA
Channel On Leakage Current	I <sub>COM(on)</sub>	V+ = 5.5  V, V- = -5.5  V, $V_{NO}, V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Room Full	- 1 - 10		1 10	
Digital Control	<u>.                                    </u>						
Input Current <sup>a</sup>	I <sub>INL</sub> or I <sub>INH</sub>		Full	- 1	0.05	1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	$R_L = 300 \ \Omega$ , $C_L = 35 \ pF$ $V_{NO}$ , $V_{NC} = \pm 3.5 \ V$ , See Figure 2	Room Full		56	74 81	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>		Room Full		42	64 67	ns
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 Only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	2			
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		112		рС
Off Isolation <sup>e</sup>	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$	Room		- 56		٩D
Channel-to-Channel Crosstalke	X <sub>TALK</sub>	$n_L = 30.52, O_L = 3 \text{ pr}, r = 1 \text{ with 12}$	Room		- 82		dB
Source Off Capacitance <sup>e</sup>	C <sub>NO(off)</sub> C <sub>NC(off)</sub>		Room		38		
Drain Off Capacitance <sup>e</sup>	C <sub>COM(off)</sub>	f = 1 MHz	Room		38		pF
Channel On Capacitance <sup>e</sup>	C <sub>COM(on)</sub>		Room		89		
Power Supplies							
Positive Supply Current <sup>e</sup>	l+		Room Full		0.03	1 5	
Negative Supply Current <sup>e</sup>	I-	$V_{IN} = 0$ or $V_{L}$	Room Full	- 1 - 5	- 0.002		μΑ
Logic Supply Current <sup>e</sup>	IL	IIV – O OI VE	Room Full		0.002	1 5	μΛ
Ground Current <sup>e</sup>	I <sub>GND</sub>		Room Full	- 1 - 5	- 0.002		ĺ



SPECIFICATIONS <sup>a</sup> Single Supply 5 V							
		Test Conditions Unless Specified V+ = 5 V, V- = 0 V		Limits - 40 °C to 85 °C		Unit	
Parameter	Symbol	$V_L = 5 \text{ V}, V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp.b	Min. <sup>d</sup>	Typ. <sup>c</sup>	Max. <sup>d</sup>	
Analog Switch							
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full			5	V
On-Resistance <sup>e</sup>	R <sub>ON</sub>	$V+ = 4.5 \text{ V}, I_{NO}, I_{NC} = 50 \text{ mA}$ $V_{COM} = 1 \text{ V}, 3.5 \text{ V}$	Room Full		3.4	4.8 5.8	Ω
Dynamic Characteristics							
Turn-On Time <sup>e</sup>	$t_{ON}$	$R_L$ = 300 Ω, $C_L$ = 35 pF	Room Hot		71	86 106	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC} = 3.5 V$ , See Figure 2	Room Hot		37	51 56	ns
Break-Before-Make Time Delay <sup>e</sup>	t <sub>D</sub>	DG9426 Only, $V_{NO}$ , $V_{NC}$ = 3.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5			
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_{g} = 0 \text{ V}, R_{g} = 0 \Omega, C_{L} = 1 \text{ nF}$	Room		10		рС
Power Supplies							
Positive Supply Current <sup>e</sup>	l+		Room Hot		0.02	1 5	
Negative Supply Current <sup>e</sup>	l-	V 0 V	Room Hot	- 1 - 5	- 0.002		
Logic Supply Current <sup>e</sup>	l∟	$V_{IN} = 0$ or $V_L$	Room Hot		0.002	1 5	μΑ
Ground Current <sup>e</sup>	I <sub>GND</sub>		Room Hot	- 1 - 5	- 0.002		

# DG9424, DG9425, DG9426

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SPECIFICATIONS <sup>a</sup> Sing	gle Supply 3	V					
		Test Conditions Unless Specified V+ = 3 V, V- = 0 V		Limits - 40 °C to 85 °C		i °C	Unit
Parameter	Symbol	$V_L = 3 \text{ V}, V_{IN} = 2.4 \text{ V}, 0.4 \text{ V}^f$	Temp.b	Min. <sup>d</sup>	Typ.c	Max.d	
Analog Switch							
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0		3	V
On-Resistance	R <sub>ON</sub>	V+ = 2.7  V, V- = 0  V $I_{NO}, I_{NC} = 5 \text{ mA}, V_{COM} = 0.5, 2.2 \text{ V}$	Room Full		8	13.8 15.1	Ω
Switch Off Leakage Current <sup>a</sup>	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 3.3 V, V- = 0 V	Room Full	- 1 - 10		1 10	
Switch On Leakage Current	I <sub>COM(off)</sub>	$V_{COM} = 0.3, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room Full	- 1 - 10		1 10	nA
Channel On Leakage Current <sup>a</sup>	I <sub>COM(on)</sub>	V+ = 3.3  V,  V- = 0  V, $V_{NO}, V_{NC} = V_{COM} = 0.3, 3 \text{ V}$	Room Full	- 1 - 10		1 10	
Digital Control <sup>e</sup>							
Input Current	I <sub>INL</sub> or I <sub>INH</sub>		Full	- 1	0.005	1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \Omega$ , $C_L = 35 pF$	Room Full		140	163 193	
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ , $V_{NC}$ = 1.5 V, See Figure 2	Room Full		65	80 89	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG9426 Only, $V_{NO}$ , $V_{NC}$ = 1.5 V $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF	Room	5			
Charge Injection <sup>e</sup>	Q <sub>INJ</sub>	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room		15		рС
Off Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega, C_L = 5 pF$	Room		- 56		dB
Channel-to-Channel Crosstalke	X <sub>TALK</sub>	f = 1 MHz	Room		- 80		ав
Source Off Capacitance <sup>e</sup>	$C_{NO(off)} \ C_{NC(off)}$		Room		53		_
Drain Off Capacitance <sup>e</sup>	C <sub>COM(off)</sub>	f = 1 MHz	Room		42		pF
Channel On Capacitance <sup>e</sup>	C <sub>COM(on)</sub>		Room		92		

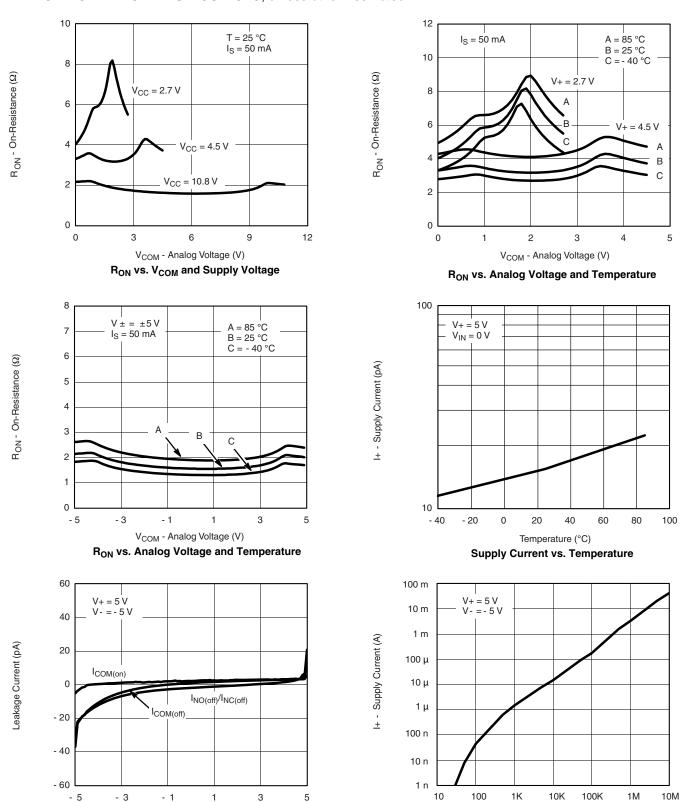
#### Notes:

- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



V<sub>COM</sub>, V<sub>NO</sub>, V<sub>NC</sub> - Analog Voltage

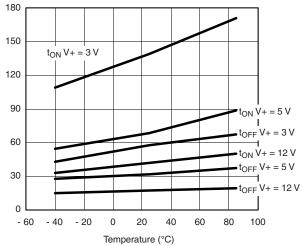
Leakage Current vs. Analog Voltage

Input Switching Frequency (Hz)

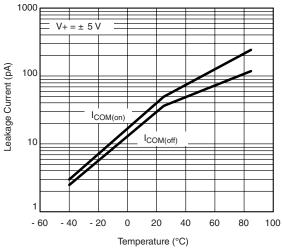
**Switching Current vs. Input Switching Frequency** 

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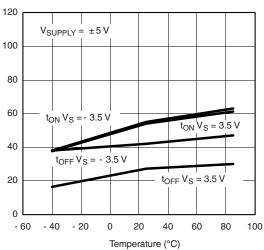
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



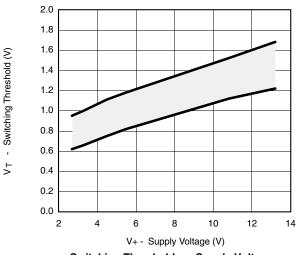
Switching Time vs. Temperature and Single Supply Voltage



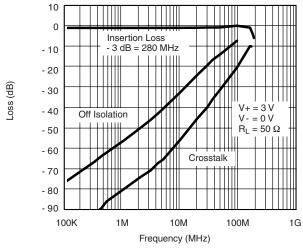
Leakage Current vs. Temperature



Switching Time vs. Temperature and Dual Supply Voltage



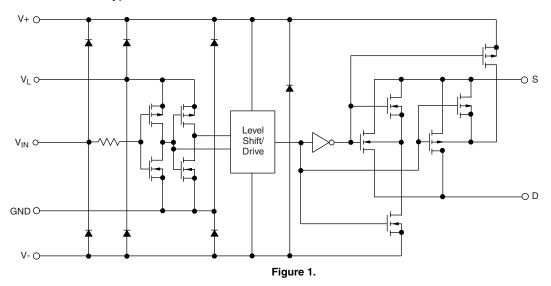
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency



#### **SCHEMATIC DIAGRAM** Typical Channel



#### **TEST CIRCUITS**

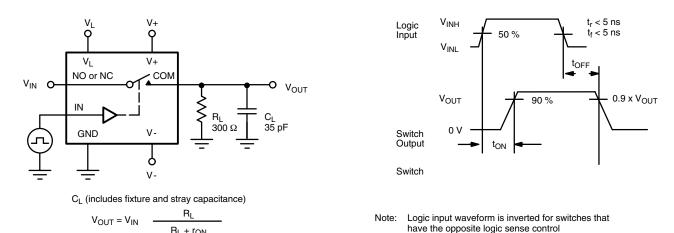


Figure 2. Switching Time

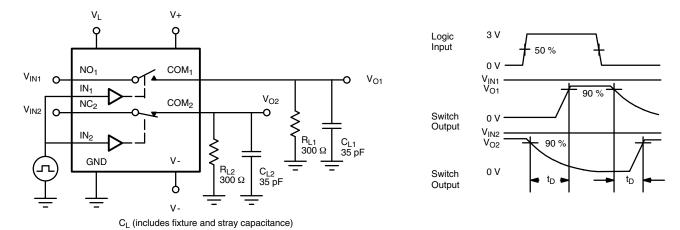


Figure 3. Break-Before-Make (DG9426)

#### **TEST CIRCUITS**



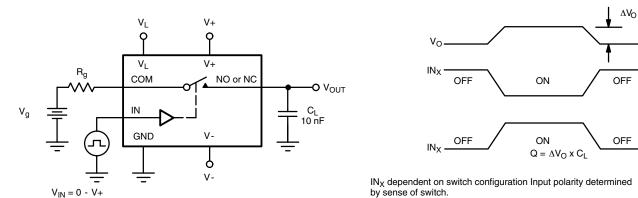


Figure 4. Charge Injection

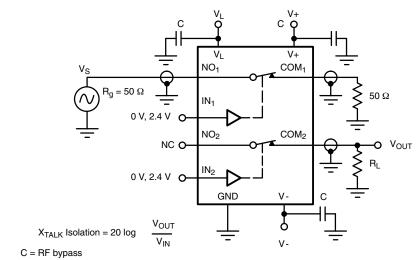
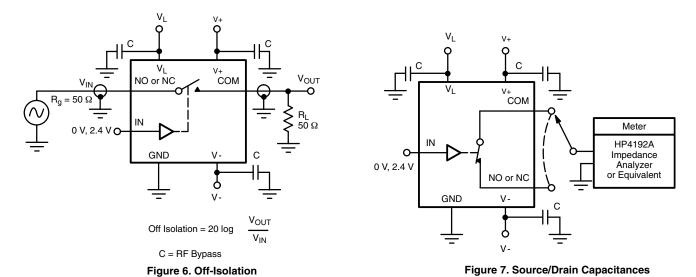


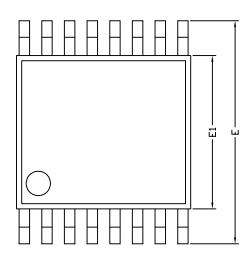
Figure 5. Crosstalk

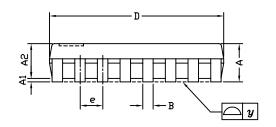


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**TSSOP: 16-LEAD** 







	DII	MENSIONS IN MILLIMETER	RS
Symbols	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
В	0.22	0.28	0.38
С	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	-	-	0.10
θ1	0°	3°	6°
FCN: S-61920-Bev D 23-	Oct-06	<u>.</u>	

ECN: S-61920-Rev. D, 23-Oct-06

DWG: 5624

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23-Oct-06
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#### **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



### **Legal Disclaimer Notice**

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